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P1 98.2



COMPOUND FIELD EFFECT POWER TRANSISTOR

μPA1526

N-CHANNEL POWER MOS FET ARRAY SWITCHING TYPE

DESCRIPTION

The μ PA1526 is N-channel Power MOS FET Array that built in 4 circuits designed for solenoid, motor and lamp driver.

FEATURES

- 4 V driving is possible
- Large Current and Low On-state Resistance

 $ID(pulse) = \pm 8 A$

RDS(on) \leq 0.30 Ω TYP. (VGS = 10 V)

RDS(on) $\leq 0.35 \Omega$ TYP. (Vgs = 4 V)

• 2.54 mm Pitch (0.1 inch)

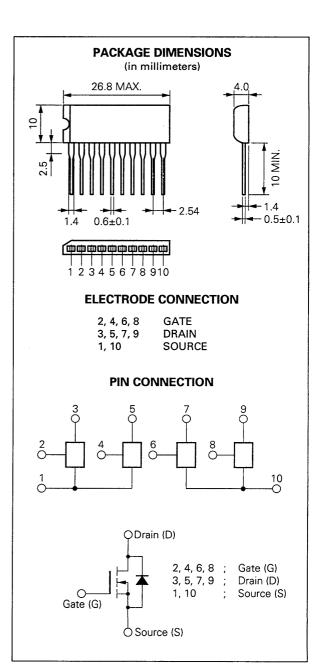
ORDERING INFORMATION

Part Number	Package	Quality Grade		
μ PA1526 H	10-Pin SIP	Standard		

Please refer to "Quality grade on NEC Semiconductor Devices" (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

ABSOLUTE MAXIMUM RATINGS (Ta = 25 °C)

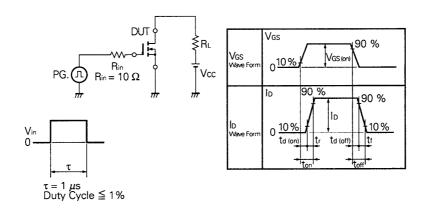
Drain to Source Voltage	Voss	100	V
Gate to Source Voltage	Vgss(AC	±20	V
Drain Current (DC)	ID(DC)	±2.0	A/unit
Drain Current (pulse)	D(pulse)	±8.0	A/unit
Total Power Dissipation (4 circuits)			
<tc 25="" =="" °c=""></tc>	P _{T1}	28	W
Total Power Dissipation (4 circuits)			
<ta 25="" =="" °c=""></ta>	PT2	3.5	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	-55 to +1	50 °C
* PW ≤ 10 ms, Duty Cycle ≤ 10 %			



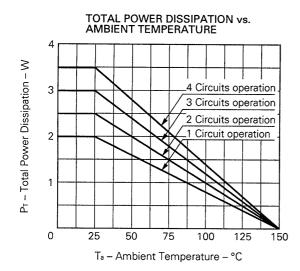
ELECTRICAL CHARACTERISTICS (Ta = 25 °C)

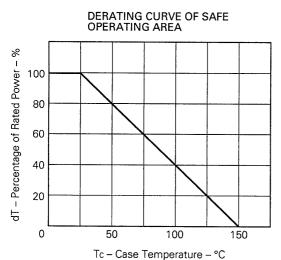
CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS	
Drain Leakage Current	Ioss			10	μΑ	VDS = 100 V, VGS = 0	
Gate to Source Leakage Current	Igss			±100	nA	$V_{GS} = \pm 20 \text{ V, } V_{DS} = 0$	
Gate to Source Cutoff Voltage	VGS(off)	1.0		2.5	V	Vps = 10 V, lp = 1 mA	
Forward Transfer Admittance	y fs	1.0			s	VDS = 10 V, ID = 1 A	
Drain to Source On-state Resistance	RDS(on)1		0.3	0.4	Ω	Vgs = 10 V, lp = 1 A	
Drain to Source On-state Resistance	RDS(on)2		0.35	0.6	Ω	Vgs = 4 V, ID = 0.8 A	
Input Capacitance	Ciss		500		pF	V _{DS} = 10 V	
Output Capacitance	Coss		120		pF	Vgs = 0	
Reverse Transfer Capacitance	Crss		30		pF	f = 1.0 MHz	
Turn-On Delay Time	td(on)		10		ns	ID = 1 A	
Rise Time	tr		20		ns	Vgs = 10 V Vcc = 50 V	
Turn-Off Delay Time	td(off)		80		ns	RL = 50 Ω , Rin = 10 Ω	
Fall Time	tf		20		ns	See Fig. 1	

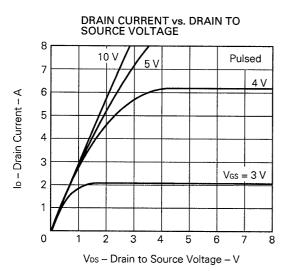
Fig. 1 Switching Test Circuit

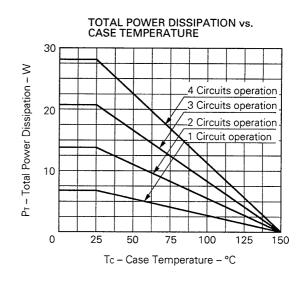


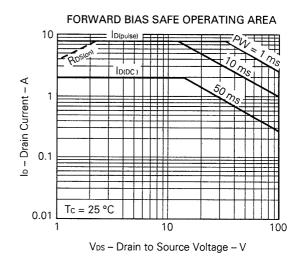
TYPICAL CHARACTERISTICS (Ta = 25 °C)

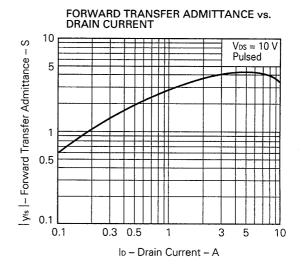


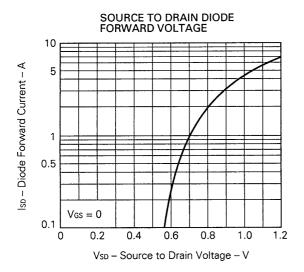


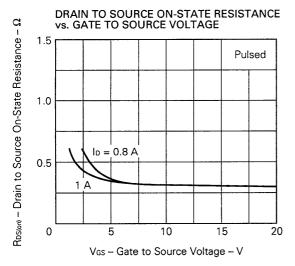


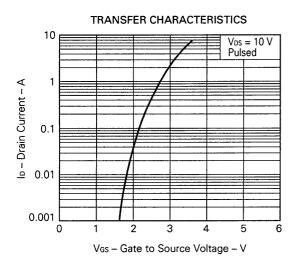


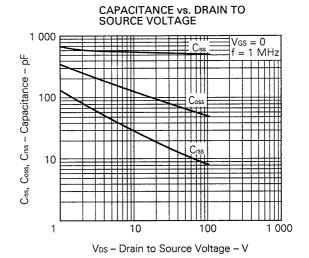


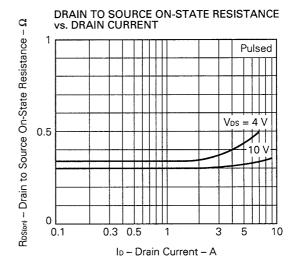


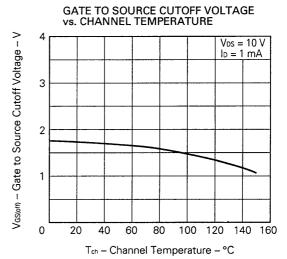


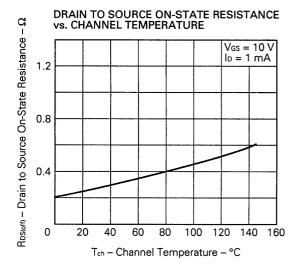












Reference

Application note name	No.
Quality control of NEC semiconductors devices.	TEI-1202
Quality control guide of semiconductors devices.	MEI-1202
Assembly manual of semiconductors devices.	IEI-1207
Safe operating area of Power MOS FET	TEA-1034
Application circuit using Power MOS FET	TEB-1035

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Application examples recommended by NEC Corporation.

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Special: Automotive and Transportation equipment, Traffic control systems, Antidisaster systems, Anticrime systems, etc.

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